# NSN 5961-01-052-7143

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# Inclosure Material:

Metal

# **Overall Length:**

Between 0.250 inches and 0.450 inches

# **Overall Diameter:**

0.875 inches

# **Mounting Facility Quantity:**

2

## Internal Configuration:

Junction contact

# Electrode Internally-electrically Connected To Case:

Collector

**Mounting Method:** 

Unthreaded hole

Semiconductor Material:

Silicon

## Voltage Rating In Volts Per Characteristic:

140.0 breakdown voltage, collector-to-base, emitter open and 120.0 breakdown voltage, collector-to-emitter, base open and 8.0 breakdown voltage, emitter-to-base, collector open

bleakdown voltage, enniter-to-base, collector

# Current Rating Per Characteristic:

Between 5.00 amperes source cutoff current and 10.00 amperes source cutoff current

# Power Rating Per Characteristic:

60.0 watts small-signal input power, common-collector

# Maximum Operating Tempurature Per Measurement Point:

200.0 degrees celsius junction

## **Special Features:**

Junction pattern arrangement: npn

## **Terminal Type And Quantity:**

2 uninsulated wire lead and 1 case

## Shelf Life:

N/a

## Unit Of Measure:

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## Demilitarization:

No

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